

DM54S195/DM74S195 4-Bit Parallel Access Shift Registers

General Description

These 4-bit registers feature parallel inputs, parallel outputs, J- \overline{K} serial inputs, shift/load control input, and a direct overriding clear. All inputs are buffered to lower the input drive requirements. The registers have two modes of operation:

Parallel (broadside) load

Shift (in the direction Q_A toward Q_D)

Parallel loading is accomplished by applying the four bits of data and taking the shift/load control input low. The data is loaded into the associated flip-flop and appears at the outputs after the positive transition of the clock input. During loading, serial data flow is inhibited.

Shifting is accomplished synchronously when the shift/load control input is high. Serial data for this mode is entered at the J- \overline{K} inputs. These inputs permit the first stage to perform as a J- \overline{K} , D, or T-type flip-flop as shown in the truth table.

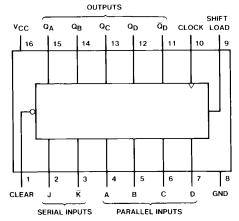
The high-performance S195, with a 105 MHz typical shift frequency, is particularly attractive for very high-speed data processing systems. In most cases existing systems can be upgraded merely by using this Schottky-clamped shift register

Features

- Synchronous parallel load
- Positive-edge-triggered clocking
- Parallel inputs and outputs from each flip-flop
- Direct overriding clear
- J and K inputs to first stage
- Complementary outputs from last stage
- For use in high-performance: accumulators/processors serial-to-parallel, parallel-to-serial converters
- Typical clock frequency 105 MHz
- Typical power dissipation 350 mW

Connection Diagram

Dual-In-Line Package



Order Number DM54S195J or DM74S195N See NS Package Number J16A or N16E TL/F/6476-1

Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage 7V
Input Voltage 5.5V
Operating Free Air Temperature Range

Storage Temperature Range -65°C to $+150^{\circ}\text{C}$

Note: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Recommended Operating Conditions

Symbol	Paramete		DM54S195	5		Units				
	Faramett	Min	Nom	Max	Min	Nom	Max	Units		
V _{CC}	Supply Voltage	4.5	5	5.5	4.75	5	5.25	٧		
V _{IH}	High Level Input Voltage	Э	2			2			V	
V _{IL}	Low Level Input Voltage			0.8			0.8	V		
I _{OH}	High Level Output Curre			-1			-1	mA		
l _{OL}	Low Level Output Curre			20			20	mA		
f _{CLK}	Clock Frequency (Note	0	105	70	0	105	70	MHz		
f _{CLK}	Clock Frequency (Note 2)		0	90	60	0	90	60	MHz	
t _W	Pulse Width	Clock	7			7			ns	
	(Note 3)	Clear	12			12				
t _{SU}	J Setup Time	Shift/Load	11			11			ns	
	(Note 3)	Data	5			5			115	
t _H	Data Hold Time (Note 3)		3			3			ns	
t _{REL}	Shift/Load Release Time (Note 3)		6			6			ns	
	Clear Release Time (Note 3)		9			9				
T _A	Free Air Operating Tem	-55		125	0		70	°C		

Note 1: $C_L=$ 15 pF, $R_L=$ 280 $\!\Omega,\,T_A=$ 25°C and $V_{CC}=$ 5V.

Note 2: $C_L = 50 \text{ pF}$, $R_L = 280\Omega$, $T_A = 25^{\circ}\text{C}$ and $V_{CC} = 5\text{V}$.

Note 3: $T_A = 25^{\circ}C$ and $V_{CC} = 5V$.

Electrical Characteristics over recommended operating free air temperature (unless otherwise noted)

Symbol	Parameter	Conditions		Min	Typ (Note 4)	Max	Units	
V_{I}	Input Clamp Voltage	$V_{CC} = Min, I_I = -18 \text{ mA}$				-1.2	V	
V_{OH}	High Level Output	$V_{CC} = Min, I_{OH} = Max$	DM54	2.5	3.4		V	
	Voltage	$V_{IL} = Max, V_{IH} = Min$	DM74	2.7	3.4			
V _{OL}	Low Level Output Voltage	$V_{CC} = Min, I_{OL} = Max$ $V_{IH} = Min, V_{IL} = Max$				0.5	V	
I _I	Input Current @ Max Input Voltage	$V_{CC} = Max, V_I = 5.5V$				1	mA	
I _{IH}	High Level Input Current	$V_{CC} = Max, V_I = 2.7V$				50	μΑ	
I _{IL}	Low Level Input Current	$V_{CC} = Max, V_I = 0.5V$				-2	mA	
los	Short Circuit	V _{CC} = Max	DM54	-40		-100	mA	
	Output Current	(Note 5)	DM74	-40		-100		
Icc	Supply Current	V _{CC} = Max (Note 6)			70	109	mA	

Note 4: All typicals are at $V_{CC} = 5V$, $T_A = 25^{\circ}C$.

Note 5: Not more than one output should be shorted at a time, and the duration should not exceed one second.

Note 6: With all inputs open, SHIFT/LOAD grounded, and 4.5V applied to the J, K, and data inputs, I_{CC} is measured by applying a momentary ground, then 4.5V to the CLEAR and then applying a momentary ground then 4.5V to

$\textbf{Switching Characteristics} \text{ at V}_{CC} = 5 \text{V and T}_{A} = 25 ^{\circ}\text{C (See Section 1 for Test Waveforms and Output Load)}$

Symbol	Parameter	From (Input) To (Output)	C _L =	15 pF	C _L =	Units	
		To (Output)	Min	Max	Min	Max	
fMAX	Maximum Clock Frequency		70		60		MHz
t _{PLH}	Propagation Delay Time Low to High Level Output	Clock to Any Q		12		15	ns
t _{PHL}	Propagation Delay Time High to Low Level Output	Clock to Any Q		16.5		20	ns
t _{PHL}	Propagation Delay Time High to Low Level Output	Clear to Any Q		18.5		23	ns

Function Table

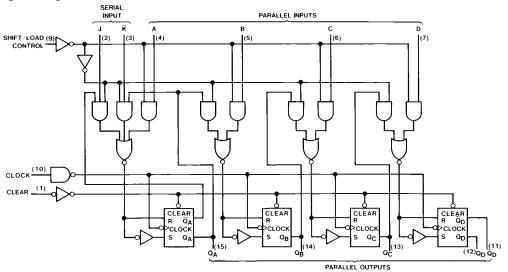
Inputs								Outputs					
Clear	Shift/ Load	Clock	Serial		Parallel			Q_{A}	Q _B	Q _C	Q _D	\overline{Q}_{D}	
			J	K	Α	В	С	D	СД	αB	Q.C	Q _D	α _D
L	Х	Х	Х	Χ	Х	Х	Х	Χ	L	L	L	L	Н
Н	L	1 1	X	Х	а	b	С	d	а	b	С	d	₫
Н	Н	L	X	Х	Х	Х	Х	Х	Q_{A0}	Q _{B0}	Q _{C0}	Q _{D0}	\overline{Q}_{D0}
Н	Н	1 1	L	Н	Х	X	Х	Х	Q _{A0}	Q _{A0}	Q _{Bn}	Q _{Cn}	\overline{Q}_{Cn}
Н	Н	1	L	L	Х	Х	Х	Х	L	Q_{An}	Q_{Bn}	Q _{Cn}	\overline{Q}_{Cn}
Н	Н	1	Н	Н	Х	X	X	X	Н	Q _{An}	Q _{Bn}	Q _{Cn}	\overline{Q}_{Cn}
Н	Н	1	Н	L	Х	X	Х	Х	\overline{Q}_{An}	Q _{An}	Q _{Bn}	Q _{Cn}	\overline{Q}_{Cn}

 $H = High \ Level \ (steady \ state), \ L = Low \ Level \ (steady \ state), \ X = Don't \ Care \ (any \ input, \ including \ transitions)$

 $Q_{A0},\,Q_{B0},\,Q_{C0},\,Q_{D0}=\text{The level of }Q_{A},\,Q_{B},\,Q_{C},\,\text{or }Q_{D},\,\text{respectively, before the indicated steady state input conditions were established.}$

 $Q_{An},\,Q_{Bn},\,Q_{Cn}=\,\text{The level of }Q_{A},\,Q_{B},\,Q_{C},\,\text{respectively, before the most recent transition of the clock}.$

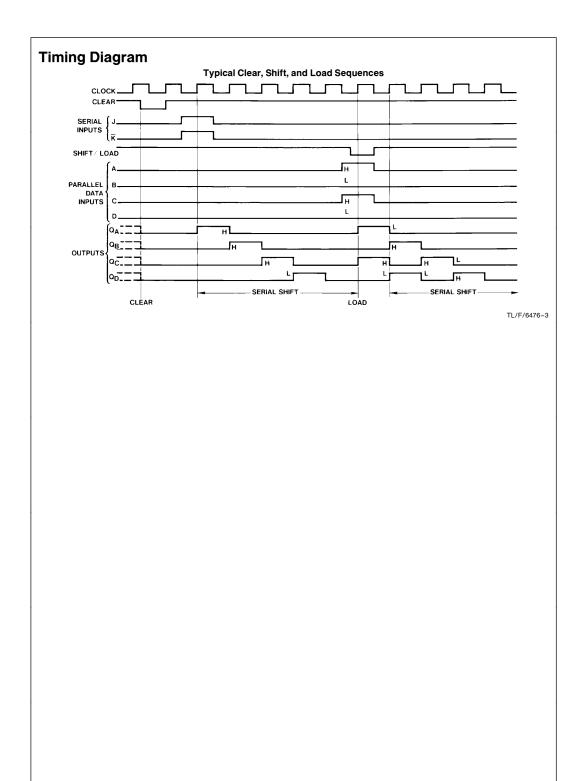
Logic Diagram

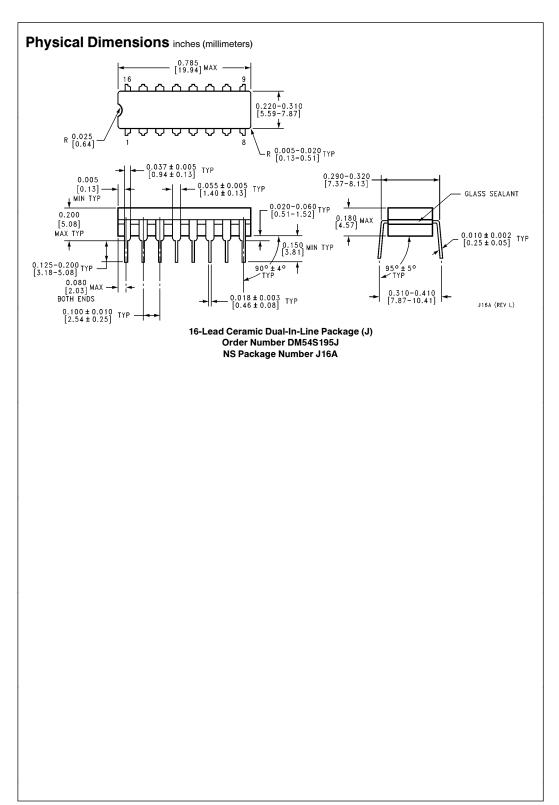


TL/F/6476-2

^{↑ =} Transition from low to high level

a, b, c, d = The level of steady state input at A, B, C, or D, respectively.





Physical Dimensions inches (millimeters) (Continued) 0.740 - 0.780 (18.80 - 19.81) (2.286)16 15 14 13 12 11 10 9 16 15 INDEX AREA 0.250 ± 0.010 (6.350 ± 0.254) PIN NO. 1 PIN NO. 1 1 2 3 4 5 6 1 2 7 | 8 OPTION 01 OPTION 02 $\frac{0.065}{(1.651)}$ $\frac{0.060}{(1.524)}$ TYP 0.300 - 0.320 (7.620 - 8.128) 4º TYP OPTIONAL $\frac{0.145 - 0.200}{(3.683 - 5.080)}$ 95°±5° $\frac{0.008 - 0.016}{(0.203 - 0.406)}$ TYP $\frac{0.020}{(0.508)}$ 0.280 $\frac{0.125 - 0.150}{(3.175 - 3.810)}$ (7.112) MIN 0.030 ± 0.015 (0.762 ± 0.381) $\frac{0.014 - 0.023}{(0.356 - 0.584)}$ $\frac{0.100 \pm 0.010}{(2.540 \pm 0.254)}$ (0.325 **+**0.040 **-**0.015

16-Lead Molded Dual-In-Line Package (N) Order Number DM74S195N NS Package Number N16E

0.050 ± 0.010

 (1.270 ± 0.254)

LIFE SUPPORT POLICY

TYP

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- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

(8.255 **+**1.016 **-**0.381



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N16E (REV F)